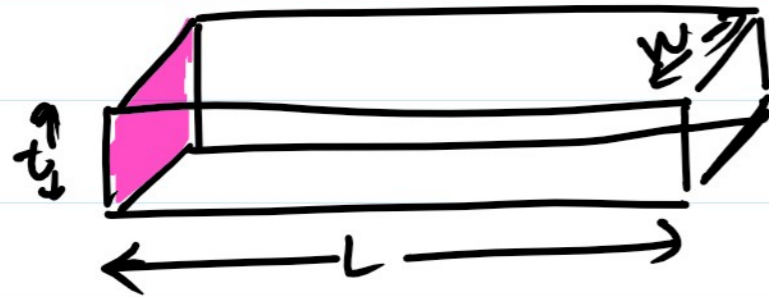


Passives R & C are integrated on-chip.

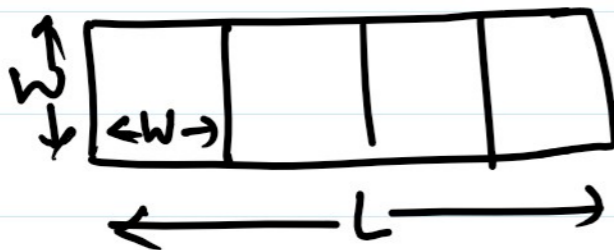
- Area of R & C is important for integration.
- PVT variations for R & C have to be compensated for desired loop dynamics.

### Resistor



$$R = \rho \frac{L}{A} \quad [\Omega]$$

$$R = \rho \times \frac{L}{w \times t}$$



$$R = \frac{\rho}{t} \frac{L}{w}$$

$$= R_{SH} \left( \frac{L}{w} \right)$$

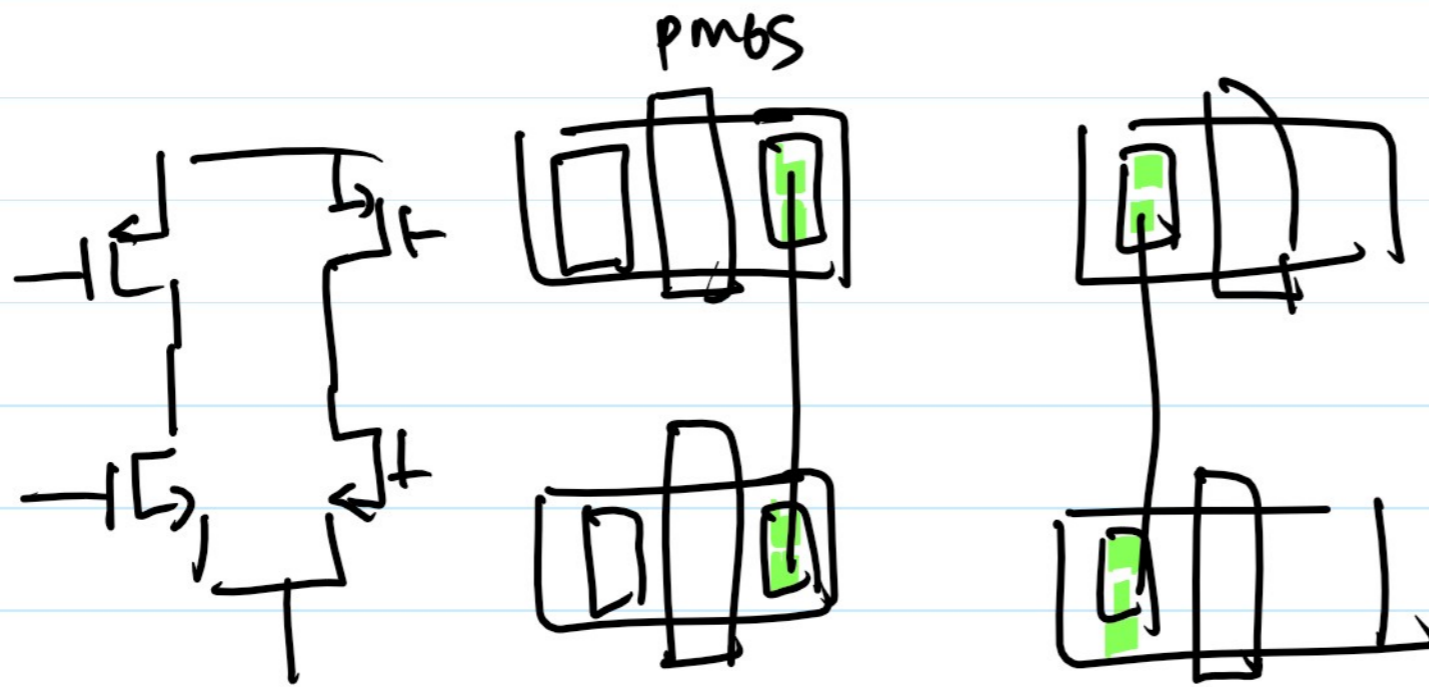
$\rho$  - resistivity of material  $[\Omega\text{-cm}]$

$R_{SH}$  - sheet resistivity  $[\Omega/\square]$

	$\rho$	
Cu	$1.7 \times 10^{-6}$	$[\Omega\text{-cm}]$
Al	$2.7 \times 10^{-6}$	
N-type Silicon	0.25	$[\Omega\text{-cm}]$
$\text{SiO}_2$	$10^{14}$	



$$R_{\text{tot}} = R_{\text{poly}} + 2 R_{\text{contact}}$$



$$R = R_{\text{sh}} \left( \frac{L}{W} \right)$$

Variation in integrated resistors

$R_{\text{sh}}$  - Doping concentration / profile

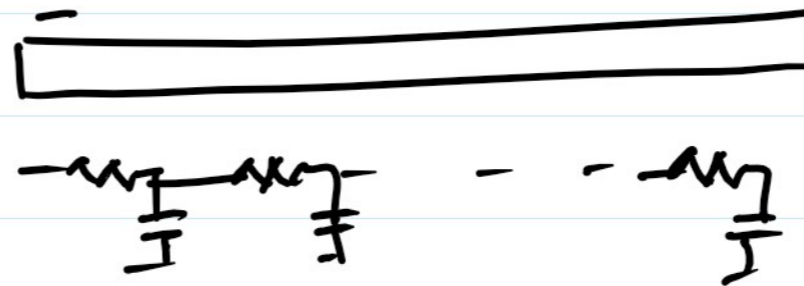
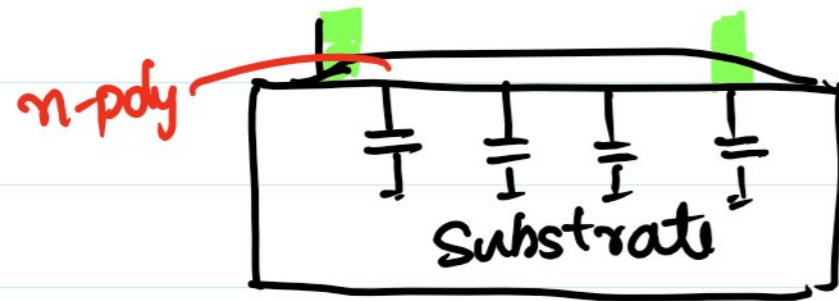
$\Delta L, \Delta W$  - Accuracy of given technology  
Lithographic techniques.

$$\frac{\Delta R}{R} = \frac{\Delta R_{sh}}{R_{sh}} + \frac{\Delta L}{L} + \frac{\Delta W}{W} \quad \pm 20-30\%$$

$$R = 1k\Omega.$$

$$L = 1\mu m, W = 0.2\mu m$$

$L = 10\mu m, W = 2\mu m$  — lesser variation ( $\pm \Delta R$ )  
larger area.



Variation in Resistance due to temperature & voltage.

$$R(T) = R(T_0) \left[ 1 + TC_1 (T - T_0) \times 10^{-6} + TC_2 (T - T_0)^2 \times 10^{-6} \right]$$

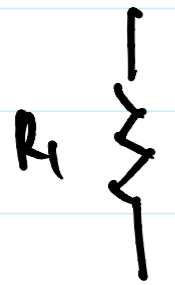
$TC_1$  - linear temp. coefficient [ppm/ $^{\circ}C$ ]

TC<sub>2</sub> quadratic // [ppm/°C]<sup>2</sup>

$$R(V) = R(V_0) [1 + VC_1 (V - V_0) \times 10^{-6} + VC_2 (V - V_0)^2 \times 10^{-6}]$$

VC<sub>1</sub> linear voltage coefficient [ppm/V]

VC<sub>2</sub> quadratic " " [ppm/V]<sup>2</sup>



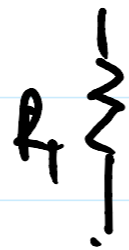
Better matching - Only n-poly } Accuracy/density  
Only p-poly }

n-poly

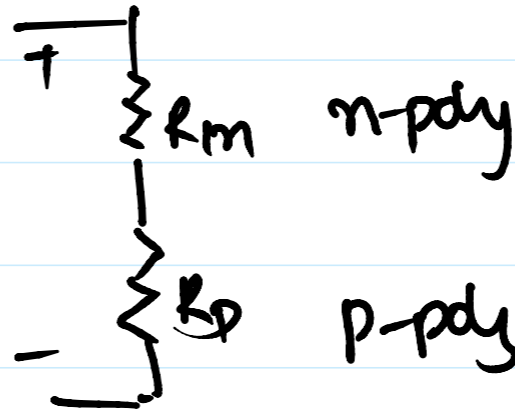
+TC<sub>1,n</sub>

p-poly

-TC<sub>1,n</sub>



≡



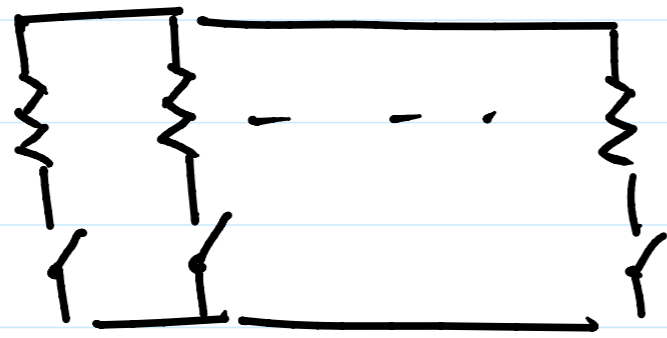
R — ± x%

a) R needs to be fixed (independent of PVT variation)

— compensate for variation

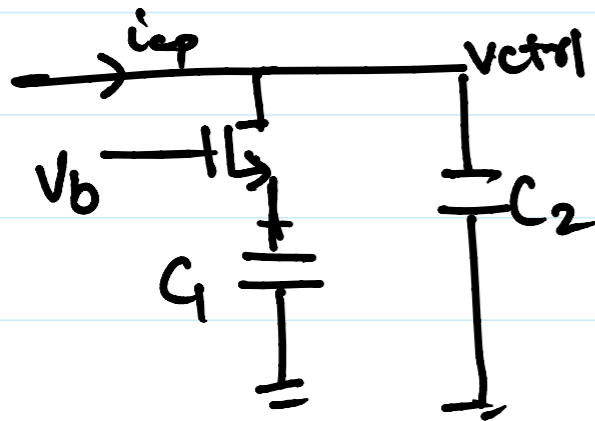
b) Wide-range PLLs — Want to change R





Resistor bank to vary  $R$ .

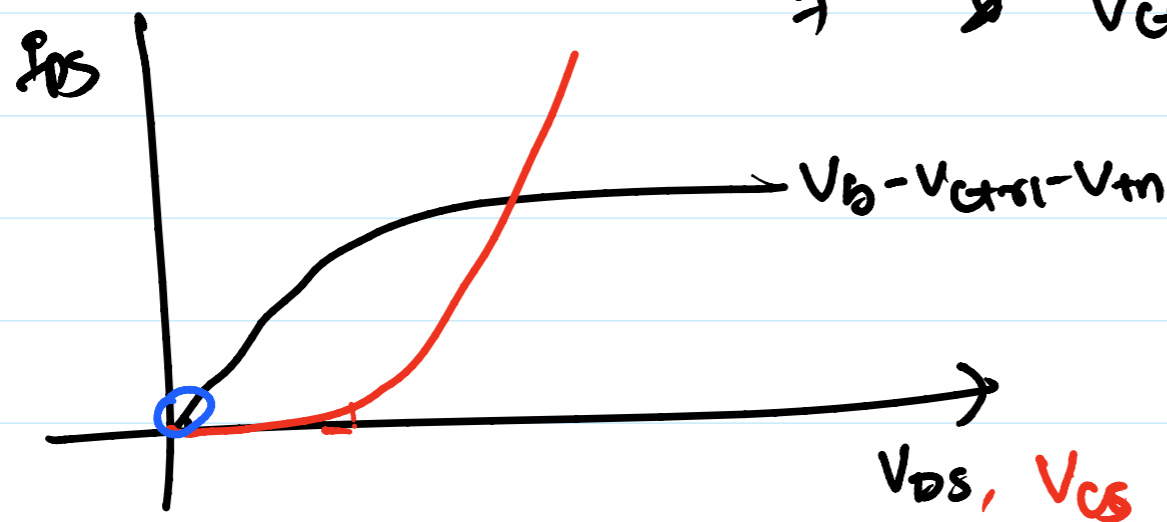
### Active Resistor



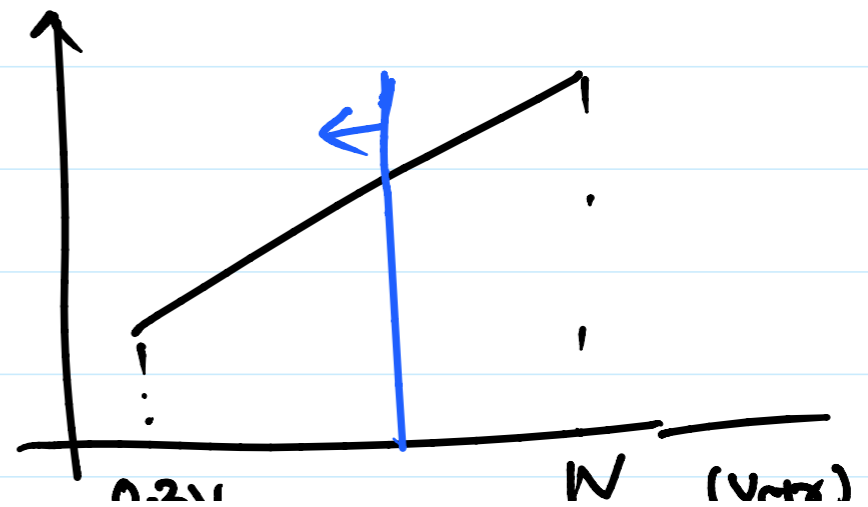
$$R_{on} = \frac{1}{\mu C_{ox} \frac{W}{L} (V_G - V_S - V_{th} - V_{DS})}$$

$$V_b - v_{ctrl} - V_{th} \geq 0$$

$$\Rightarrow v_{ctrl} \leq V_b - V_{th}$$



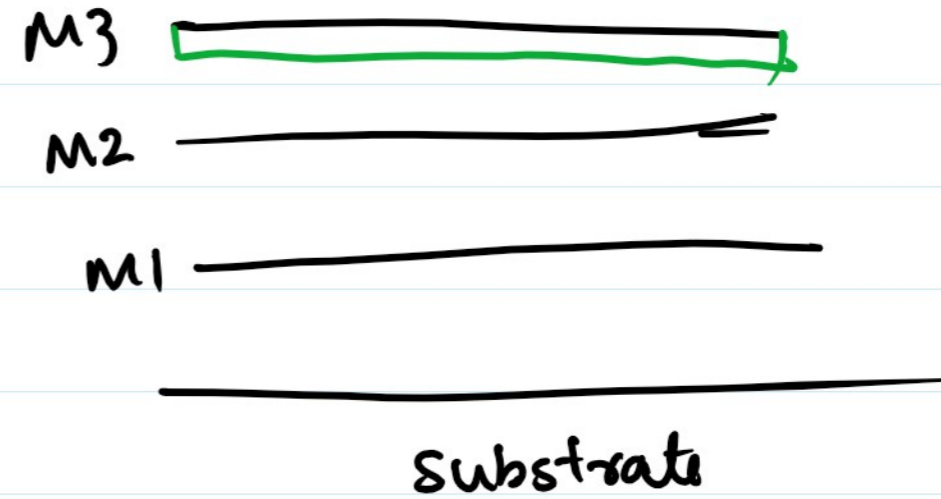
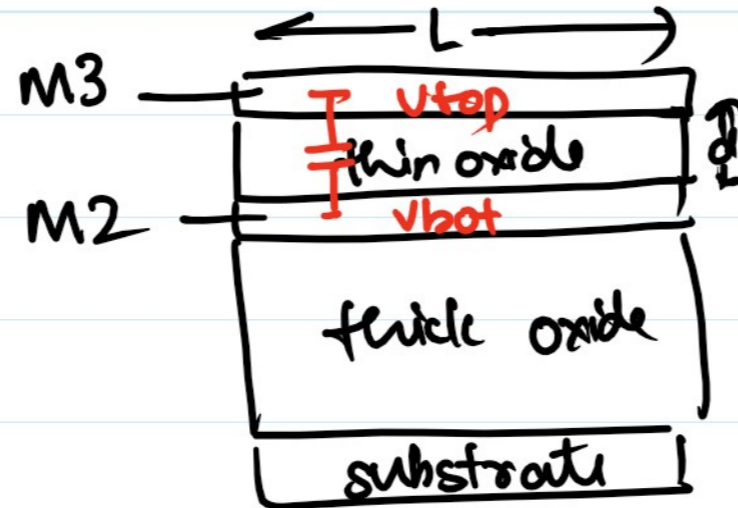
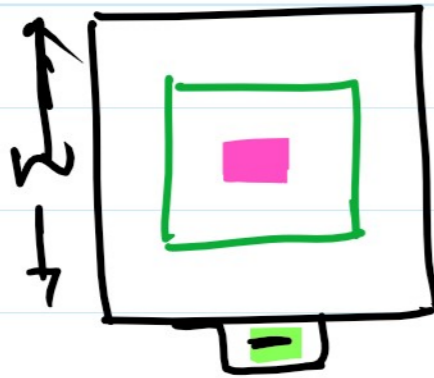
$\Rightarrow$  limits oscillation freq





# Passive Capacitor

a) Parallel plate capacitor



$$C = \epsilon \frac{A}{d}$$

